

# Chemical Science

rsc.li/chemical-science



ISSN 2041-6539



ROYAL SOCIETY  
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#### EDGE ARTICLE

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Cite this: *Chem. Sci.*, 2019, 10, 10687

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# Blue thermally activated delayed fluorescence emitters incorporating acridan analogues with heavy group 14 elements for high-efficiency doped and non-doped OLEDs†

Kyohei Matsuo ‡\*a and Takuma Yasuda \*ab

Deep-blue thermally activated delayed fluorescence (TADF) emitters are promising alternatives for conventional fluorescence and phosphorescence materials for practical application in organic light-emitting diodes (OLEDs). However, as appropriate bipolar hosts for deep-blue TADF-OLEDs are scarce, the development of efficient deep-blue TADF emitters that are applicable to both doped and non-doped systems is an urgent task. In this study, we developed a new family of blue TADF emitters that demonstrated high photoluminescence (PL) and electroluminescence (EL) quantum efficiencies in both doped and non-doped (neat) systems. Four new donor–acceptor (D–A)-type TADF molecules incorporating phenazasiline, phenazagermine, and tetramethylcarbazole as weak D units and phenothiaborin as a weak A unit were designed and synthesized. By varying the structural rigidity/flexibility as well as the electron-donating ability of the D units, the resulting photophysical and TADF properties of the D–A molecules could be systematically regulated. A comprehensive photophysical investigation revealed that phenazasiline and phenazagermine-based emitters concurrently exhibit blue TADF emissions (464–483 nm), high PL quantum efficiencies (~100%), extremely fast spin-converting reverse intersystem crossing rates ( $>10^7$  s<sup>-1</sup>), and suppressed concentration quenching. These fascinating features in conjunction produced high-performance doped and non-doped blue TADF-OLEDs. The doped and non-doped TADF-OLEDs using the phenazasiline-based emitter demonstrated extremely high maximum external EL quantum efficiencies ( $\eta_{\text{ext}}$ ) of 27.6% and 20.9%, with CIE chromaticity coordinates of (0.14, 0.26) and (0.14, 0.20), respectively. Further, ultra-low efficiency roll-off behavior for both the doped and non-doped devices was demonstrated by their  $\eta_{\text{ext}}$  as high as 26.1% and 18.2%, respectively, measured at a practically high luminance of 1000 cd m<sup>-2</sup>.

Received 6th September 2019  
Accepted 21st October 2019

DOI: 10.1039/c9sc04492b

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## Introduction

The development of high-performance blue organic light-emitting diodes (OLEDs) is of vital importance for practical applications in full-color flat-panel displays and white lighting sources, and has been attracting growing interest both academically and commercially.<sup>1</sup> In recent years, considerable research efforts have been devoted to boosting the exciton utilization for electroluminescence (EL) and thereby making

a leap forward in the resulting device efficiency. Phosphorescent emitters based on noble metal complexes have become indispensable for this task since 1998,<sup>2</sup> because of their capability of harvesting both singlet and triplet excitons with almost 100% internal quantum efficiency ( $\eta_{\text{int}}$ ) in OLEDs. Among the three primary colors, green and red phosphorescent emitters have already shown high performance in terms of both efficiency and stability, and have been successfully incorporated into commercial OLED products. Recently, highly efficient deep-blue phosphorescent OLEDs with narrow EL emissions have been produced by employing rigid tetradentate Pt(II) complexes<sup>3</sup> and *N*-heterocyclic carbene coordinated Ir(III) complexes.<sup>4</sup> However, even state-of-the-art deep-blue phosphorescent OLEDs have still lagged behind the green and red counterparts in their operational lifetime and stability, and thus, further development of deep-blue emitters *via* innovative molecular design remains an ongoing challenge.

The replacement of noble metal-containing phosphors with metal-free pure organic fluorophores is a challenging task, but

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† Electronic supplementary information (ESI) available. CCDC 1948037–1948040. For ESI and crystallographic data in CIF or other electronic format see DOI: 10.1039/c9sc04492b

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one of high priority, for realizing future low-cost OLED applications. It was not until 2012 that purely organic thermally activated delayed fluorescence (TADF) emitters were first adopted in OLEDs<sup>5</sup> and demonstrated high  $\eta_{\text{int}}$  of nearly 100%. Over the last few years, a number of organic TADF materials displaying various emission colors have been developed, and TADF-OLEDs with high external EL quantum efficiencies ( $\eta_{\text{ext}}$ ) of up to  $\sim 38\%$ , comparable to those of phosphorescent OLEDs, have been achieved.<sup>6</sup> However, deep-blue TADF materials capable of exhibiting high  $\eta_{\text{ext}}$  exceeding 20% (corresponding to  $\eta_{\text{int}}$  approximating 100%) in OLEDs as well as appropriate color purity (with Commission Internationale de l'Éclairage (CIE) chromaticity coordinates of  $x \leq 0.15$  and  $y \leq 0.20$ ) are still scarce.<sup>7</sup>

To achieve deep-blue EL, TADF molecules are required to have a wide energy gap between the highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO), as well as high lowest-excited singlet ( $S_1$ ) and triplet ( $T_1$ ) energies ( $\geq 2.8$  eV). Typically, TADF molecules adopt a donor-acceptor (D-A) electronic system, in which the HOMO and LUMO are mainly distributed on the donor and acceptor moieties, respectively, giving rise to intramolecular charge-transfer (ICT) states. Therefore, the combination of a donor having a deeper HOMO level with an acceptor having a shallower LUMO level is prerequisite for the design of deep-blue TADF emitters. While various types of acceptor units, such as triazine,<sup>7c,f,j</sup> pyrimidine,<sup>7d</sup> diphenylsulfone,<sup>7a</sup> benzophenone,<sup>7g</sup> triarylborane,<sup>7h,i</sup> and heteraborins,<sup>7b,k,l</sup> have been used for the design of deep-blue TADF molecules, candidates for relatively weak donors have been limited to carbazole and 9,10-dihydroacridine (acridan) derivatives, which restricts diversity in material design. In this regard, 5,10-dihydrodibenzo[*b,e*][1,4]azasiline (phenazasiline), which is a heavy-atom analogue of acridan, has recently been introduced for the design of blue TADF emitters by Kim and co-workers.<sup>7c,8</sup> As the C-Si bonds, which are longer than C-C bonds, reduce the electron-donating effect arising from hyperconjugation, phenazasiline can function as a weaker donor compared to acridan, and lead to blue-shifted emissions. So far, there are no systematic studies on the structural, electronic, and photophysical properties of TADF emitters based on acridan-analogous donors with heavier group 14 elements.

Another inherent bottleneck for developing efficient and stable deep-blue TADF-OLEDs is the lack of suitable host materials with a high triplet energy ( $E_T$ ) and balanced charge transport properties. An ideal host for deep-blue TADF emitters requires a high  $E_T$  level surpassing 3.0 eV to facilitate triplet energy transfer from the host to the emitters and prevent back energy transfer. However, it is technically difficult to obtain bipolar high- $E_T$  host materials owing to the limited availability of suitable building blocks.<sup>9</sup> This issue can be circumvented by adopting non-doped (neat) emission layers instead of conventional guest-host systems. The non-doped devices require advanced blue TADF emitters with (i) a high photoluminescence (PL) quantum yield ( $\Phi_{\text{PL}}$ ) in the neat film, (ii) short excited-state lifetime to alleviate concentration quenching, and (iii) a favorable bipolar charge transport property.

Except for a few recent examples,<sup>10</sup> most reported blue TADF emitters bearing carbazole-based donors undergo severe aggregation-caused emission quenching (ACQ) and red-shift or broadening of the PL emission caused by intermolecular interactions in the condensed phase. Recent works by our group<sup>7b,11,12</sup> and Wu, Wong, and co-workers<sup>13</sup> reported non-doped and heavily-doped TADF-OLEDs with acridan-based emitters, which achieved rather high maximum  $\eta_{\text{ext}}$  values. We also revealed the ACQ mechanism for TADF systems and succeeded in retaining high  $\Phi_{\text{PL}}$  in the pure neat films without using any host materials.<sup>11a</sup> Hence, the utilization of acridan-based donors is regarded as a versatile design strategy for efficient non-doped TADF systems; however, achieving blue TADF with a CIE- $y$  value ( $\leq 0.20$ ) remains a major challenge because of the strong electron-donating characteristics of the acridan-based donors. More recently, aggregation-induced delayed fluorescence (AIDF) has been proposed as a new viable methodology to avoid ACQ and hence produce efficient non-doped OLEDs.<sup>14</sup> However, thus far, efficient deep-blue AIDF systems that are capable of fulfilling the aforementioned criteria have not been attained.

In this study, we focused on the electronic and structural features of a set of acridan-analogous donors with different group 14 (crystallogen) elements, and systematically designed new TADF emitters **1-4** by combining them with phenothiazoborin (BS) as the common acceptor unit (Fig. 1). Having weakened electron-donating abilities, **1-4** indeed showed blue-shifted TADF emissions (by 20–35 nm) in comparison to that of the parent acridan-appended TADF emitter **5**.<sup>12</sup> In addition, effects of their unique conformational heterogeneity on the photophysical properties and EL characteristics were systematically investigated by changing the bridging group 14 elements for the phenazasiline- and phenazagermine-appended TADF emitters. Of this new family of blue TADF emitters, **1** and **3** were found to exhibit suppressed ACQ behavior and therefore high  $\Phi_{\text{PL}}$  values even in their neat films. Owing to this advantageous attribute, non-doped TADF-OLEDs based on **1** and **3**

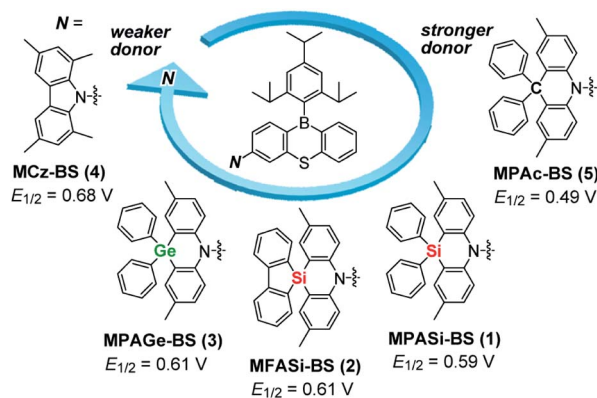


Fig. 1 Molecular structures of blue phenothiazoborin-based TADF emitters incorporating acridan-analogous donors with different group 14 elements.  $E_{1/2}$  values represent the half-wave oxidation potentials vs.  $\text{Fc}/\text{Fc}^+$  determined by cyclic voltammetry and differential pulse voltammetry (ES1†), as a measure of the electron-donating ability.





folded along their central N...Si or N...Ge axis and adopted 'quasi-axial (QA)' conformations with small D-A torsion angles (C8-C9-N-C28) of 5.1–15.8° in the crystalline states. The crystal structures of 1–3 were in marked contrast to that of 5, which preferentially formed a typical 'quasi-equatorial (QE)' conformer having a large torsion angle of  $-114.0^\circ$ .<sup>15</sup> Such conformational heterogeneity (*i.e.*, capability to form QA and QE conformers) of this series of D-A molecules can be attributed to the mismatch of the bridging bond lengths in each acridan-analogous donor unit; namely, Ge-C ( $\sim 1.94 \text{ \AA}$ ) > Si-C ( $\sim 1.86 \text{ \AA}$ )  $\gg$  C-C ( $\sim 1.54 \text{ \AA}$ ) > N-C ( $\sim 1.44 \text{ \AA}$ ). Some TADF molecules, most frequently those with a sulfur-containing phenothiazine donor, reportedly show intriguing dual CT emissions arising from two different conformers.<sup>15,16</sup> Despite the similarity in the covalent radii of sulfur and silicon, effects of such conformational heterogeneity of phenazasiline and its derivatives on the optical and electronic properties have never been clarified.

To gain further insight into the QA-QE conformational interconversion, we performed computational simulations using density functional theory (DFT), as presented in Fig. 3 (see ESI for details<sup>†</sup>). For the MPAsi-appended 1 as a representative example, three stable conformations with different D-A torsion angles were predicted in the ground ( $S_0$ ) state, which corresponded to one QA and two QE conformers (Fig. 3a). The torsion angle of the QA conformer for 1 was as small as  $6.0^\circ$ , consistent with the foregoing crystal structure. In contrast, much larger torsion angles ( $-93.4^\circ$  and  $88.3^\circ$ ) were estimated for its two QE conformers (QE1 and QE2). In this case, the free energy differences ( $\Delta G$ ) between the QA and QE conformers were estimated to be considerably small ( $< 0.6 \text{ kcal mol}^{-1}$ ). The interconversion energy barriers calculated for 1 ( $4.8\text{--}5.7 \text{ kcal mol}^{-1}$ ) appeared to be small enough for allowing free conformational changes in solution at room temperature. Likewise, the geometry optimizations for 2, 3, and 5 performed following the same protocol indicated three local minima corresponding to one QA and two QE conformers (Fig. 3b). For 5 with the less crooked MPAC donor, two QE conformers were further energetically stabilized (by  $2.7\text{--}2.8 \text{ kcal mol}^{-1}$ ) with respect to the corresponding QA conformer. This suggests that the QE conformer with the nearly orthogonal D-A arrangement should have a higher population at equilibrium. Contrary to 1, 2, and 5, the calculated free energies of the two QE conformers for 3 were higher than the QA one (by  $2.1\text{--}2.4 \text{ kcal mol}^{-1}$ ), implying that the QA conformation was thermodynamically more preferable for the phenazagermine derivative. As the interconversion energy barriers did not change significantly with the variation of the donor units, the population ratios of the QA and QE conformers for 1, 2, 3, and 5 could be estimated using their  $\Delta G$  values by assuming Boltzmann distribution. Consequently, for 1, 2, and 5, the orthogonal QE conformers were expected to have much higher populations (QE = 70%, 87%, and 99%, respectively); in contrast, the QA conformer for 3 predominated over the QE conformer (QA = 98% and QE = 2%) at room temperature. These results unambiguously indicate that a structural modification in the bridging moiety of the donor units has a marked

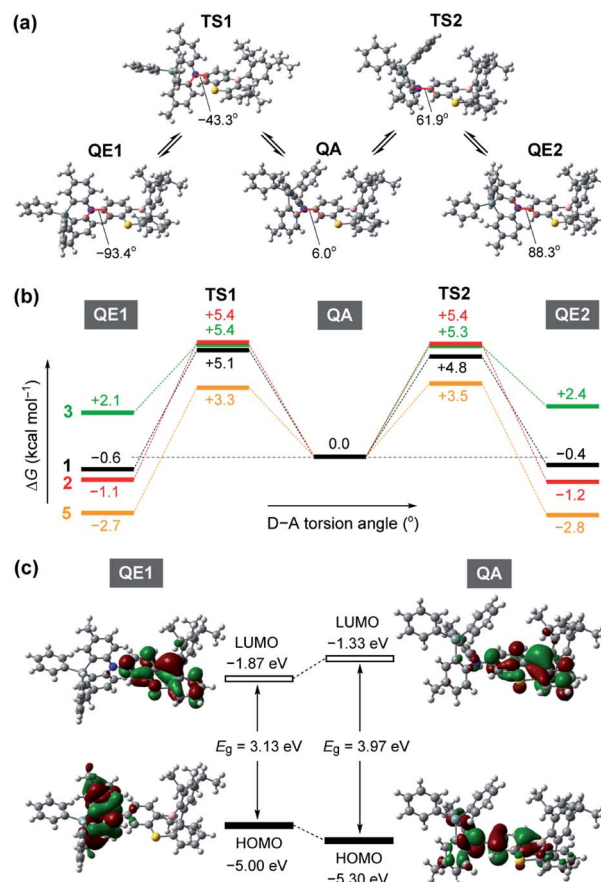


Fig. 3 (a) Molecular geometrical changes in 1 along the interconversion between its quasi-equatorial (QE) and quasi-axial (QA) conformers through the transition states (TS). (b) Energy profiles for the interconversion processes of 1–3 and 5 in their ground states at 298 K and 1 atm, calculated at the B3LYP/6-31G(d) level of theory. (c) Spatial distribution of the frontier orbitals (HOMOs and LUMOs) for the ground-state QE and QA conformers of 1.

impact on the intrinsic conformational flexibility and heterogeneity.

Fig. 3c depicts the HOMO and LUMO distributions of both QE and QA conformers of 1 in the  $S_0$  state. Similar to common TADF molecules with an orthogonal D-A arrangement, there was negligible spatial HOMO–LUMO overlap in the QE conformer for 1, in which the HOMO and LUMO were localized on the phenazasiline donor and phenothiaborin acceptor moieties, respectively, exhibiting evident ICT characteristics. In contrast, the QA conformation of 1 could reduce the D-A distortion and thereby facilitate the conjugation of the lone pair of the nitrogen atom with the adjacent phenothiaborin moiety. Consequently, its HOMO and LUMO were overlapped on the acceptor moiety, giving them a more localized electronic transition character. Furthermore, this QA conformer was found to have a deeper (or more stabilized) calculated HOMO level and also wider HOMO–LUMO energy gap ( $E_g$ ) compared to the QE conformer. Very similar computational results were obtained for 2 and 3 as well (ESI<sup>†</sup>), revealing the notably different electronic transition characteristics between the interconvertible QE and QA conformers.





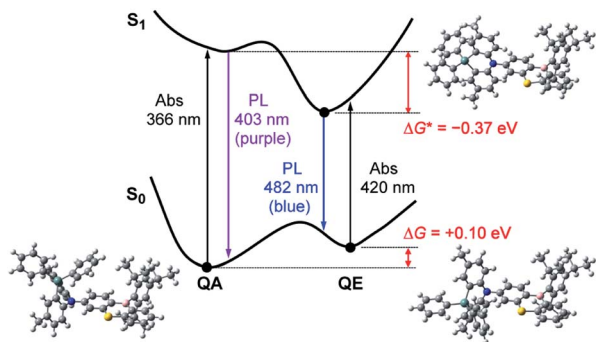


Fig. 5 Schematic energy level diagram for **3** exhibiting the mechanism of excited-state interconversion and dual PL emissions in toluene solution. The optimized structures of the QA and QE conformations in the  $S_0$  state and the orthogonal conformation in the  $S_1$  state calculated at the B3LYP/6-31G(d) level are presented.

predominant blue emissions from the QE conformers in the solution PL spectra of **1–3**.

### Photophysical properties and exciton dynamics in thin films

To unveil their potential as blue TADF emitters prior to device fabrication, the photophysical properties of **1–4** were investigated in both doped and neat films, as presented in Fig. 6. For doped films, bis(diphenylphosphoryl)dibenzo[*b,d*]furan (PPF,  $E_T = 3.1$  eV) was employed as a wide-gap high- $T_1$  host to effectively confine the  $S_1$  and  $T_1$  excitons in the TADF emitters. The detailed photophysical data are summarized in Table 1. All doped films of **1–4** displayed intense blue PL emissions ( $\lambda_{PL} = 468–483$  nm) with notably high absolute  $\Phi_{PL}$  values of 92–100% under  $N_2$  atmosphere (Fig. 6a and c). Interestingly, unlike dilute solutions, the emission from the QA conformers completely disappeared in the doped films of **1** and **2**. Given that large structural relaxation cannot occur easily in the solid state, the intensified QE emissions likely originated for another reason. Because of the spectral overlap between the QA emission and QE absorption, the excited energy of the QA conformer could be transferred to the QE conformer by Förster resonance energy transfer (FRET), dissipating the emission from the QA conformer in these doped films. However, only the doped film of **3** exhibited a clear QA emission at  $\sim 400$  nm as a shoulder, which was ascribed to an incomplete FRET due to a tiny proportion of the QE conformer in its initial  $S_0$  equilibrium. The absorption spectra of the neat films of **1–3** (Fig. 6d) were nearly the same as those measured in toluene solution, which suggests that the neat films were composed of mixtures of their QA and QE conformers having population ratios equivalent to those in the solution. As listed in Table 1, the  $\Delta E_{ST}$  values of **1–4** were estimated as small as 0.08, 0.06, 0.11, and 0.11 eV, respectively, from the energy differences between the onsets of the fluorescence and low-temperature phosphorescence spectra of the doped films (ESI†).

Interestingly, the PL spectra of **1–3** were blue-shifted and became narrower in the neat films (Fig. 6b and Table 1), as compared to those of the doped films. This behavior can be

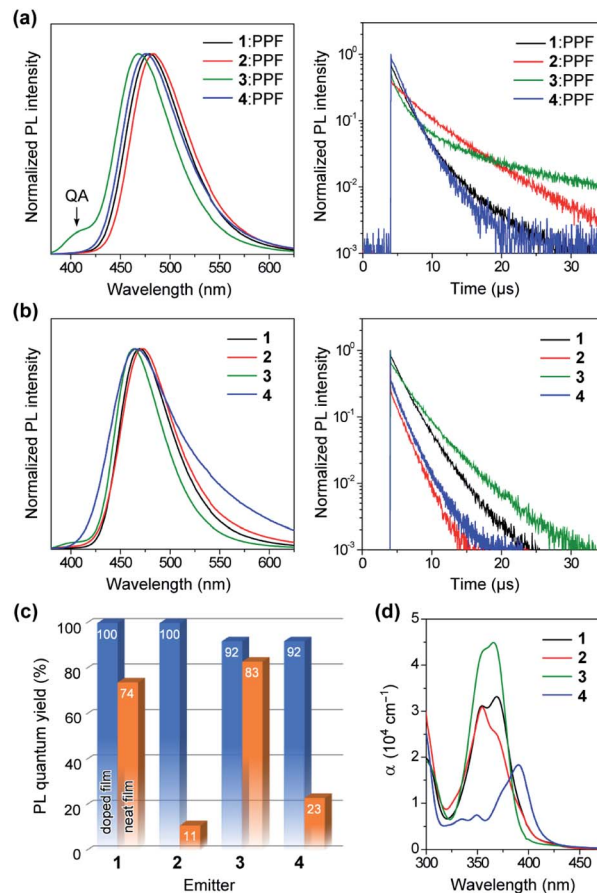


Fig. 6 (a and b) Steady-state PL spectra (left) and transient PL decay profiles (right) of **1–4** in (a) 50 wt%-emitter:PPF doped films and (b) pure neat films measured at 300 K under  $N_2$ . (c) Comparison of  $\Phi_{PL}$  values measured with **1–4** in the doped and neat films. (d) UV-vis absorption spectra of the neat films of **1–4**.

explained by the difference in the polarity of the surrounding solid host media. Compared to the highly polar PPF host, the less polar nature of **1–3** as host media implied a lower degree of stabilization for the polar ICT excited states, thus leading to hypsochromic shifts of PL emissions in the neat films. Moreover, owing to their terminal bulky substituents, **1** and **3** were capable of suppressing ACQ and thereby exhibited considerably high  $\Phi_{PL}$  of 74% and 83%, respectively, even in the aggregated neat films (Fig. 6c). This feature is favorable for the fabrication of non-doped blue OLEDs (as will be discussed later). In contrast, the neat film of **4** bearing the planar MCz donor gave a broadened PL spectrum and a much lower  $\Phi_{PL}$ , similar to the cases of conventional TADF emitters, presumably because of intermolecular electron-exchange interactions between the neighboring MCz moieties in the aggregated state.<sup>11a</sup>

To verify the TADF nature, the transient PL characteristics of **1–4** were examined in both doped and neat films (Fig. 6a and b, right). All transient PL decay curves could be fitted using a double-exponential model, giving prompt fluorescence lifetimes in the nanosecond regime ( $\tau_p = 0.5–3.4$  ns) and delayed fluorescence lifetimes in the microsecond regime ( $\tau_d = 1.7–10.4$   $\mu$ s). It is worth noting that each decay curve of the doped films



Table 1 Photophysical data of 1–4 in doped and neat films

Emitter <sup>a</sup>	$\lambda_{\text{PL}}^b$ [nm]	$E_{\text{FWHM}}^c$ [eV]	$\lambda_{\text{FWHM}}^c$ [nm]	$\phi_{\text{PL}}^d$ [%]	$\phi_{\text{p}}^e$ [%]	$\phi_{\text{d}}^e$ [%]	$\tau_{\text{p}}^f$ [ns]	$\tau_{\text{d}}^f$ [ $\mu\text{s}$ ]	$k_{\text{r}}^g$ [ $10^6 \text{ s}^{-1}$ ]	$k_{\text{ISC}}^h$ [ $10^8 \text{ s}^{-1}$ ]	$k_{\text{RISC}}^i$ [ $10^7 \text{ s}^{-1}$ ]	$\Delta E_{\text{ST}}^j$ [eV]
1	Dope	0.36	69	100	1.1	98.9	2.9	2.7	3.9	3.5	3.3	0.08
	Neat	0.34	62	74	0.6	73.4	0.95	2.3	6.1	10	5.4	
2	Dope	0.35	68	100	1.4	98.6	3.4	5.3	4.1	2.9	1.3	0.06
	Neat	0.35	68	11	0.8	10.2	1.3	1.7	6.4	7.8	0.74	
3	Dope	0.37	67	92	0.5	91.5	1.7	10.4	3.2	5.9	1.6	0.11
	Neat	0.32	57	83	0.7	82.3	0.95	3.2	7.0	10	3.9	
4	Dope	0.37	70	92	0.8	91.2	1.7	1.9	4.7	5.9	5.9	0.11
	Neat	0.46	85	23	0.4	22.6	0.54	1.8	6.6	18	3.6	

<sup>a</sup> Measured as a 50 wt% doped thin film in a PPF host matrix (Dope) or pure neat film (Neat) at 300 K under  $N_2$ . <sup>b</sup> PL emission maximum. <sup>c</sup> Full width at half-maximum of the PL spectrum given in energy or wavelength. <sup>d</sup> Absolute PL quantum yield evaluated using an integrating sphere from overall QA and QE emissions. <sup>e</sup> Fractional quantum yields for prompt fluorescence ( $\phi_{\text{p}}$ ) and delayed fluorescence ( $\phi_{\text{d}}$ );  $\phi_{\text{p}} + \phi_{\text{d}} = \phi_{\text{PL}}$ . <sup>f</sup> Emission lifetimes for prompt fluorescence ( $\tau_{\text{p}}$ ) and delayed fluorescence ( $\tau_{\text{d}}$ ). <sup>g</sup> Rate constant of fluorescence radiative decay ( $S_1 \rightarrow S_0$ );  $k_{\text{r}} = \phi_{\text{p}}/\tau_{\text{p}}$ . <sup>h</sup> Rate constant of ISC ( $S_1 \rightarrow T_1$ );  $k_{\text{ISC}} = (1 - \phi_{\text{p}})/\tau_{\text{p}}$ . <sup>i</sup> Rate constant of RISC ( $T_1 \rightarrow S_1$ );  $k_{\text{RISC}} = \phi_{\text{d}}/(k_{\text{ISC}}\tau_{\text{d}}\phi_{\text{p}})$ . <sup>j</sup> Singlet-triplet energy splitting determined from the lowest excited singlet ( $E_{\text{S}}$ ) and triplet ( $E_{\text{T}}$ ) energies by  $\Delta E_{\text{ST}} = E_{\text{S}} - E_{\text{T}}$  (see ESI).

contained a trace portion of prompt fluorescence with a very small fractional quantum yield ( $\Phi_{\text{p}} = 0.5\text{--}1.5\%$ ) while most of the PL originated from delayed fluorescence ( $\Phi_{\text{d}} = 91\text{--}99\%$ ). This ideal TADF behavior can be attributed to their capability of fast intersystem crossing (ISC) and reverse ISC (RISC). Indeed, extremely large ISC and RISC rate constants ( $k_{\text{ISC}}$  and  $k_{\text{RISC}}$ ) exceeding  $10^8$  and  $10^7 \text{ s}^{-1}$  were evaluated for 1–4, as listed in Table 1. These  $k_{\text{ISC}}$  and  $k_{\text{RISC}}$  values were approximately one and two orders of magnitude greater, respectively, than the corresponding fluorescence radiative decay rate constant ( $k_{\text{r}} \sim 10^6\text{--}10^7 \text{ s}^{-1}$ ). Therefore, the rate-limiting step in the TADF processes of 1–4 is now the fluorescence radiative decay ( $S_1 \rightarrow S_0$ ) rather than RISC ( $T_1 \rightarrow S_1$ ), which is completely opposite to conventional TADF materials that have much lower  $k_{\text{RISC}}$  ( $<10^6 \text{ s}^{-1}$ ). To the best of our knowledge, the  $k_{\text{RISC}}$  values obtained for 1–4 ( $>10^7 \text{ s}^{-1}$ ) are the highest among all TADF emitters ever reported, irrespective of the emission colors. This result is closely associated with the fact that the  $\Phi_{\text{d}}$  dominated the overall  $\Phi_{\text{PL}}$  values, enabling nearly 100% ISC efficiencies ( $\Phi_{\text{ISC}} = 1 - \Phi_{\text{p}}$ ) and 92–100% RISC efficiencies ( $\Phi_{\text{RISC}} = \Phi_{\text{d}}/\Phi_{\text{ISC}}$ ) for 1–4.<sup>20</sup>

We further investigated the excited-state electronic properties of 1–4 using TD-DFT (LC- $\omega$ PBE/6-31+G(d)) calculations. As can be seen from Fig. 7, the optimized  $S_1$  states of 1–4 (with the emissive QE conformation) were dominated by the HOMO  $\rightarrow$  LUMO ICT transitions ( $^1\text{CT}$ ). In contrast, their optimized lowest  $T_1$  states were mainly associated with the HOMO–1 (or HOMO–2)  $\rightarrow$  LUMO transitions ( $^3\text{LE}$ ), corresponding to the  $\pi\text{--}\pi^*$  transition of the phenothiazine acceptor moiety. Indeed, the measured  $E_{\text{T}}$  of the phenothiazine precursor (Br-BS, 2.78 eV) was nearly the same as those of 1–4 ( $E_{\text{T}} = 2.76\text{--}2.81 \text{ eV}$ , ESI<sup>†</sup>), supporting the implication that the  $\pi\text{--}\pi^*$  transition of the phenothiazine moiety was from their most relevant  $T_1$  states. The adiabatic  $\Delta E_{\text{ST}}$  values for 1–4 were calculated to be 37, 61, 146, and 112 meV, respectively, which are in satisfactory agreement with the experimental  $\Delta E_{\text{ST}}$  values. It was also found that the upper-lying  $T_2$  states, which are represented by triplet ICT ( $^3\text{CT}$ ), lay at slightly higher energies than the corresponding  $T_1$  states. One can anticipate that RISC is intrinsically allowed between the  $^3\text{LE}$  and  $^1\text{CT}$  states with effective spin-orbit coupling (SOC), ( $^1\text{CT}|H_{\text{SOC}}|^3\text{LE}$ ), because of the vanishing of the SOC between  $^3\text{CT}$  and  $^1\text{CT}$  states having the same spatial orbital occupation (*i.e.*,  $\langle ^1\text{CT}|H_{\text{SOC}}|^3\text{CT} \rangle \approx 0$ ).<sup>12,21</sup> The predominant  $^3\text{LE}$  component (79–97%) in the lowest  $T_1$  states of 1–4 is thus beneficial to the spin-converting RISC processes, in addition to having small  $\Delta E_{\text{ST}}$  values.

### OLED device performance

To evaluate the EL performances of 1–4 as blue TADF emitters, we first fabricated doped OLEDs (devices A–D) employing 50 wt%-emitter:PPF doped films as the emission layer (EML). The fabricated device structure was indium tin oxide (ITO, 50 nm)/HAT-CN (10 nm)/TAPC (50 nm)/CCP (10 nm)/EML (20 nm)/PPF (10 nm)/B3PyPB (30 nm)/LiQ (1 nm)/Al (100 nm), where 2,3,6,7,10,11-hexacyano-1,4,5,8,9,12-hexaazatriphenylene (HAT-CN), 1,1-bis[4-*N,N*-di(*p*-tolyl)amino]phenyl]cyclohexane (TAPC), 9-phenyl-3,9'-bicarbazole (CCP), 1,3-bis[3,5-di(pyridin-3-yl)





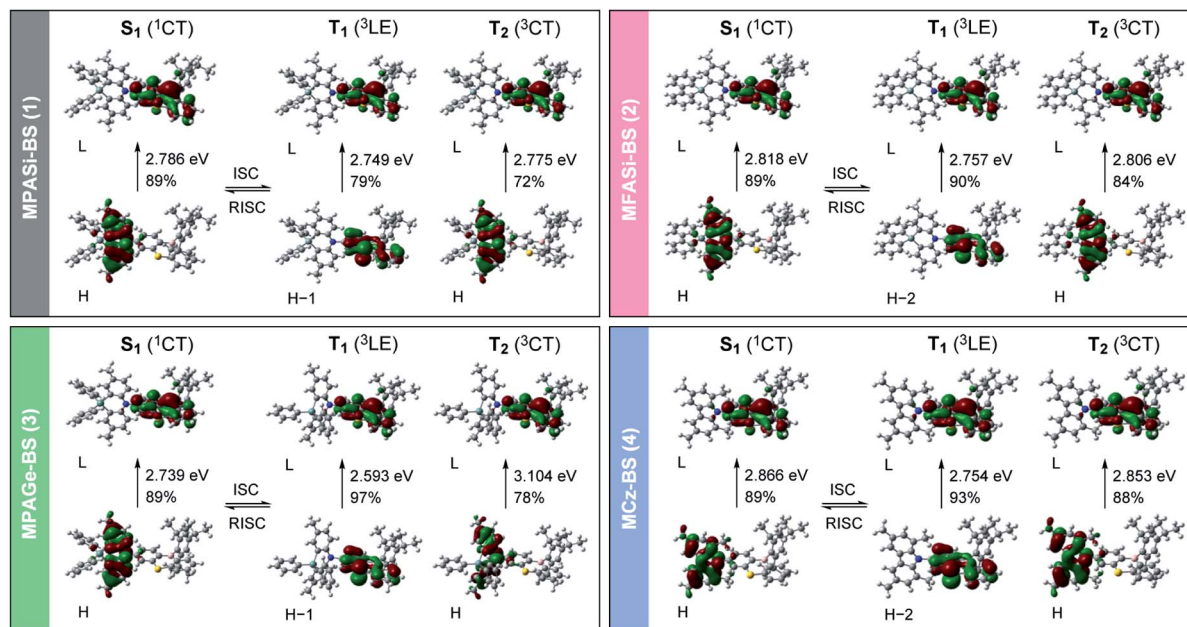


Fig. 7 Electronic transition characteristics and associated frontier orbital distributions for the excited  $S_1$ ,  $T_1$ , and  $T_2$  states of **1–4** calculated using TD-DFT (LC- $\omega$ PBE/6-31+G(d)) at the optimized  $S_1$  or  $T_1$  geometries. The values on each arrow represent the adiabatic excitation energy and contribution weight of the depicted orbitals (H = HOMO; L = LUMO).

phenyl]benzene (B3PyPB), and 8-hydroxyquinolinolato lithium (Liq) layers play the roles of hole injection, hole transport, exciton and electron block, electron transport, and electron injection, respectively. A detailed energy level diagram of the devices is provided in ESI.† As the HOMO and LUMO energy levels of emitters **1–4** ( $E_{\text{HOMO}} = -5.7$  to  $-5.9$  eV and  $E_{\text{LUMO}} = -2.7$  to  $-3.0$  eV) are shallower and deeper, respectively, than those of the PPF host ( $-6.7$  and  $-2.7$  eV), electrically injected holes and electrons can be directly trapped on the guest emitter molecules to effectively generate excitons within the EML.

Fig. 8a–c shows the EL spectra, current density–voltage–luminance ( $J$ – $V$ – $L$ ) characteristics, and  $\eta_{\text{ext}}$  versus  $L$  plots for the doped devices A–D, while Table 2 compiles the key EL parameters. Devices A–D displayed blue to sky-blue EL with the emission peaks ( $\lambda_{\text{EL}}$ ) ranging from 476 to 484 nm, similar to the corresponding PL spectra. The turn-on voltages ( $V_{\text{on}}$ ) of these devices were as low as 2.8–3.2 V, which were comparable to the photo-excited  $S_1$  energies of **1–4** ( $E_{\text{S}} = 2.8$ – $2.9$  V), suggesting a direct charge recombination and exciton generation mechanism. Comparing the performances of the TADF emitters **1–4** among devices A–D, the maximum  $\eta_{\text{ext}}$  values were in the order of **1** (27.6%) > **2** (23.9%) > **4** (21.6%) > **3** (15.7%). Particularly, device A using **1** achieved the best EL performance with a maximum  $\eta_{\text{ext}}$  of 27.6%, current efficiency ( $\eta_{\text{c}}$ ) of 48.7 cd A $^{-1}$ , power efficiency ( $\eta_{\text{p}}$ ) of 48.7 lm W $^{-1}$ , and CIE coordinates of (0.14, 0.26). Furthermore, device A demonstrated ultra-low efficiency roll-off; the  $\eta_{\text{ext}}$  values remained as high as 27.5% at 100 cd m $^{-2}$  (for display), 26.1% at 1000 cd m $^{-2}$  (for lighting), and 18.7% even at 10000 cd m $^{-2}$ , corresponding to approximately 0.3%, 5%, and 32% roll-offs, respectively, relative to the maximum  $\eta_{\text{ext}}$  value. This suppressed efficiency roll-off in

device A is even smaller than those of state-of-the-art blue TADF-OLEDs.<sup>7</sup> In spite of the same  $\Phi_{\text{PL}}$  values for the doped films of **3** and **4**, device C using **3** exhibited much lower  $\eta_{\text{ext}}$  ( $\leq 15.5\%$ ) over the entire luminance range, which was attributed to the low population of its emissive QE conformer causing a reduced exciton generation probability, even in the heavily-doped EML. In device C, the excitons are formed mainly on the major QA conformer of **3**, and then excited energy transfer to the emissive QE conformer takes place. As the population of the QE conformer is significantly low, the generated excitons are lost to some extent *via* incomplete energy transfer, resulting in lower EL efficiencies.<sup>15b</sup> In addition, the different length dependence of the energy transfer processes for singlet and triplet excitons seems to be relevant to the discrepancy of the trend between the PL and EL efficiencies.<sup>22</sup> Since only the singlet excitons are initially generated upon photoexcitation, effective energy transfer from the QA to QE conformers takes place *via* long-range Förster mechanism and hence, efficient TADF emission from the QE conformer can be achieved in the PL process with a high  $\Phi_{\text{PL}}$  value. In contrast, under electrical excitation in OLEDs, additional short-range Dexter energy transfer, which is much more sensitive to the interchromophore distance, should cause incomplete energy transfer to the emissive QE conformer and lowering the EL efficiency. This can be supported by the fact that the non-doped OLED (device F) with a higher content of the QE conformer within the EML exhibited a higher EL efficiency than the corresponding doped OLED (device C).

The specifically low ACQ characteristics of **1** and **3** in the neat films prompted us to further evaluate the EL performance in the host-free non-doped devices. To this end, we fabricated the non-doped TADF-OLEDs (devices E and F) by adopting the neat films



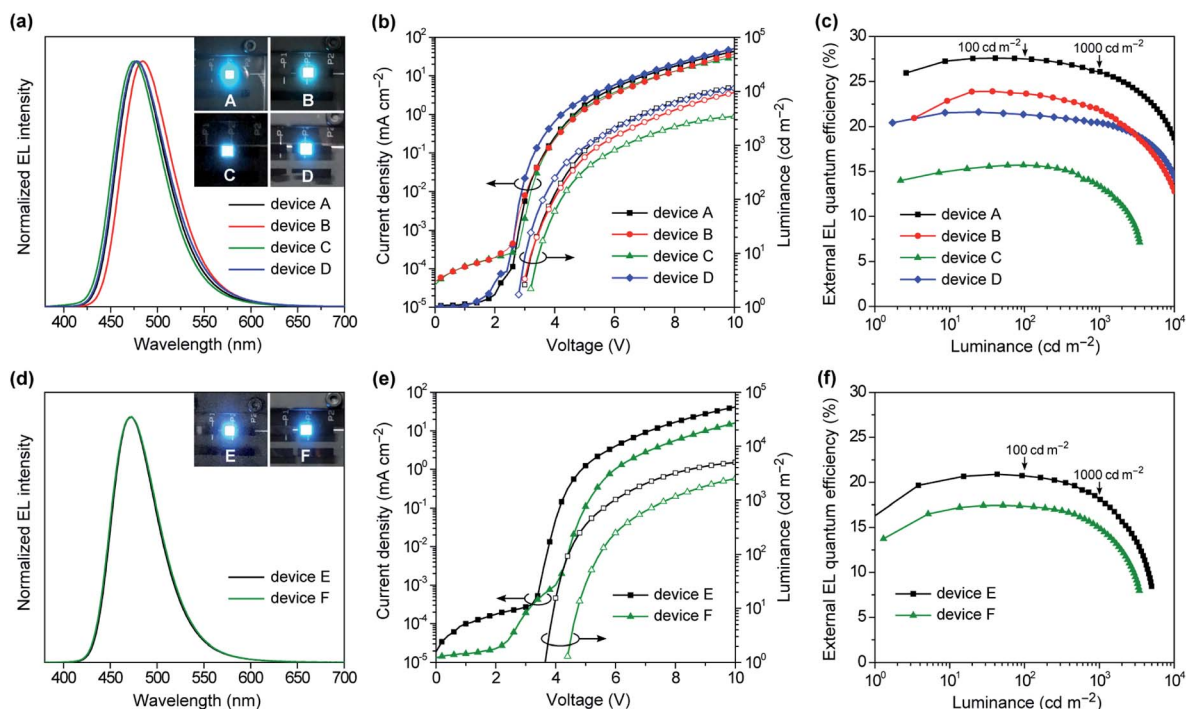


Fig. 8 EL characteristics for (a–c) doped TADF-OLEDs (devices A–D) based on 50 wt% 1–4:PPF and (d–f) non-doped TADF-OLEDs (devices E and F) based on 1 and 3: (a and d) EL spectra measured at  $10 \text{ mA cm}^{-2}$  and photos of blue EL emissions, (b and e)  $J$ - $V$ - $L$  characteristics, and (c and f)  $\eta_{\text{ext}}$  versus  $L$  plots.

Table 2 EL performances of the TADF-OLEDs based on 1–4

Device	EML <sup>a</sup>	$\lambda_{\text{EL}}^b$ [nm]	$E_{\text{FWHM}}^c$ [eV]	$\lambda_{\text{FWHM}}^c$ [nm]	CIE <sup>d</sup> [x, y]	$V_{\text{on}}^e$ [V]	$\eta_{\text{ext,max}}^f$ [%]	$\eta_{\text{ext,100/1000/10000}}^g$ [%]	$\eta_c^h$ [cd A <sup>-1</sup> ]	$\eta_p^i$ [lm W <sup>-1</sup> ]
A	1:PPF	478	0.33	61	(0.14, 0.26)	3.0	27.6	27.5/26.1/18.7	48.7	48.7
B	2:PPF	484	0.32	62	(0.14, 0.32)	3.0	23.9	23.7/21.9/12.9	47.8	45.0
C	3:PPF	476	0.33	62	(0.14, 0.22)	3.2	15.7	15.5/13.2/—	24.8	22.5
D	4:PPF	478	0.34	64	(0.14, 0.26)	2.8	21.6	21.3/20.4/14.4	39.0	41.9
E	1	473	0.31	57	(0.14, 0.20)	3.6	20.9	20.7/18.2/—	30.1	23.8
F	3	473	0.32	59	(0.14, 0.20)	4.4	17.4	17.4/14.9/—	25.7	16.9

<sup>a</sup> Emission layer consisting of a codeposited 50 wt%-emitter:PPF doped film (for devices A–D) or a non-doped neat film (for devices E and F). <sup>b</sup> EL emission maximum at  $10 \text{ mA cm}^{-2}$ . <sup>c</sup> Full width at half-maximum of the EL spectrum given in energy (eV) or wavelength (nm). <sup>d</sup> CIE chromaticity coordinates. <sup>e</sup> Turn-on voltage at a luminance above  $1 \text{ cd m}^{-2}$ . <sup>f</sup> Maximum external EL quantum efficiency. <sup>g</sup> External EL quantum efficiency at the luminance of 100, 1000, and 10000  $\text{cd m}^{-2}$ . <sup>h</sup> Maximum current efficiency. <sup>i</sup> Maximum power efficiency.

of 1 and 3 instead of the doped films as the EML, with the same device configuration. Devices E and F exhibited slightly blue-shifted  $\lambda_{\text{EL}}$  of 473 nm with narrower bandwidths ( $E_{\text{FWHM}} = 0.31$ – $0.32$  eV and  $\lambda_{\text{FWHM}} = 57$ – $59$  nm, Fig. 8d) compared to the corresponding doped devices (A and C). Consequently, both devices E and F achieved blue CIE coordinates of (0.14, 0.20). Remarkably,  $\eta_{\text{ext}}$  of the non-doped devices E and F reached 20.9% and 17.4%, respectively (Fig. 8e and f and Table 2). Moreover, the efficiency roll-off of device E was rather low, retaining high  $\eta_{\text{ext}}$  values of 20.7% and 18.2% even when driven at practically high luminances of 100 and 1000  $\text{cd m}^{-1}$ , respectively, which are among the best performing values for the reported non-doped blue TADF-OLEDs.<sup>10–12</sup> It is also

noteworthy that device F using 3 exhibited superior EL performance to the corresponding doped device C. This result may be explained by the increased emissive QE conformers within the non-doped EML.

## Conclusions

In this study, we systematically designed and synthesized new blue TADF emitters featuring acridan-analogous donors containing silicon and germanium bridging atoms. Incorporating larger silicon and germanium atoms enhanced the structural flexibility of the donor units, leading to conformational heterogeneity as well as dual fluorescence capability of the



resulting TADF emitters. While all these TADF molecules adopted dual conformations in both solution and thin film states, efficient excited energy transfer from the QA to QE conformers took place and the latter displayed obvious TADF characteristics. As phenazasiline and phenazagermine acted as weaker electron donors than the commonly used acridan unit, bluer TADF was attained. Additionally, the direct electronic coupling between the close-lying local triplet ( $^3\text{LE}$ ) and charge-transfer singlet ( $^1\text{CT}$ ) excited states *via* SOC greatly enhanced the RISC rates ( $k_{\text{RISC}} > 10^7 \text{ s}^{-1}$ ) and thereby TADF efficiencies of the emitters. It was also found that blue TADF emitters **1** and **3** with the diphenyl-substituted phenazasiline and phenazagermine donors demonstrated surprisingly small concentration quenching behavior and were applicable to both doped and non-doped systems as efficient bifunctional emitters. The doped and non-doped blue TADF-OLEDs fabricated using **1** demonstrated excellent EL performances, with maximum  $\eta_{\text{ext}}$  as high as 27.6% and 20.9%, respectively, and suppressed efficiency roll-off at a practically high luminance. We believe that this systematic study can offer a general guideline toward precise control of the structures and photophysical and TADF properties. By utilizing the design concept demonstrated here and improving the intrinsic stability and device architectures, outstanding deep-blue TADF-OLEDs can be developed.

## Conflicts of interest

There are no conflicts to declare.

## Acknowledgements

This work was supported in part by Grant-in-Aid for JSPS KAKENHI Grant No. JP17K17937 (K. M.) and JP18H02048 (T. Y.), the Research Foundation for the Electrotechnology of Chubu (T. Y.), the Japan Research Institute of Industrial Science (T. Y.), and the Research Foundation for Opto-Science and Technology (T. Y.). K. M. is grateful for financial support from the JSPS Research fellowship (Grant No. JP18J01692). The authors are grateful for Prof. Nobuo Kimizuka and Prof. Teppei Yamada at Kyushu University for their generous permission to use the X-ray crystallography facility, and also for the support provided by the Cooperative Research Program "Network Joint Research Center for Materials and Devices" and the computer facilities at the Research Institute for Information Technology, Kyushu University.

## References

- For recent reviews, see; (a) Y. Im, S. Y. Byun, J. H. Kim, D. R. Lee, C. S. Oh, K. S. Yook and J. Y. Lee, *Adv. Funct. Mater.*, 2017, **27**, 1603007; (b) X. Cai and S.-J. Su, *Adv. Funct. Mater.*, 2018, **28**, 1802558; (c) T.-T. Bui, F. Goubard, M. Ibrahim-Ouali, D. Gigmes and F. Dumur, *Beilstein J. Org. Chem.*, 2018, **14**, 282; (d) J.-H. Lee, C.-H. Chen, P.-H. Lee, H.-Y. Lin, M.-K. Leung, T.-L. Chiu and C.-F. Lin, *J. Mater. Chem. C*, 2019, **7**, 5874.
- (a) M. A. Baldo, D. F. O'Brien, Y. You, A. Shoustikov, S. Sibley, M. E. Thompson and S. R. Forrest, *Nature*, 1998, **395**, 151; (b) M. A. Baldo, S. Lamansky, P. E. Burrows, M. E. Thompson and S. R. Forrest, *Appl. Phys. Lett.*, 1999, **75**, 4.
- (a) X.-C. Hang, T. Fleetham, E. Turner, J. Brooks and J. Li, *Angew. Chem., Int. Ed.*, 2013, **52**, 6753; (b) T. Fleetham, G. Li, L. Wen and J. Li, *Adv. Mater.*, 2014, **26**, 7116; (c) G. Li, T. Fleetham, E. Turner, X. C. Hang and J. Li, *Adv. Opt. Mater.*, 2015, **3**, 390; (d) T. B. Fleetham, L. Huang, K. Klimes, J. Brooks and J. Li, *Chem. Mater.*, 2016, **28**, 3276.
- (a) H. Sasabe, J. Takamatsu, T. Motoyama, S. Watanabe, G. Wagenblast, N. Langer, O. Molt, E. Fuchs, C. Lennartz and J. Kido, *Adv. Mater.*, 2010, **22**, 5003; (b) J. Lee, H.-F. Chen, T. Batagoda, C. Coburn, P. I. Djurovich, M. E. Thompson and S. R. Forrest, *Nat. Mater.*, 2016, **15**, 92; (c) Z. Chen, L. Wang, S. Su, X. Zheng, N. Zhu, C.-L. Ho, S. Chen and W.-Y. Wong, *ACS Appl. Mater. Interfaces*, 2017, **9**, 40497.
- (a) H. Uoyama, K. Goushi, K. Shizu, H. Nomura and C. Adachi, *Nature*, 2012, **492**, 234; (b) S. Y. Lee, T. Yasuda, H. Nomura and C. Adachi, *Appl. Phys. Lett.*, 2012, **101**, 093306; (c) A. Endo, K. Sato, K. Yoshimura, T. Kai, A. Kawada, H. Miyazaki and C. Adachi, *Appl. Phys. Lett.*, 2011, **98**, 083302.
- For reviews, see: (a) Y. Tao, K. Yuan, T. Chen, P. Xu, H. Li, R. Chen, C. Zheng, L. Zhang and W. Huang, *Adv. Mater.*, 2014, **26**, 7931; (b) M. Y. Wong and E. Zysman-Colman, *Adv. Mater.*, 2017, **29**, 1605444; (c) Y. Im, M. Kim, Y. J. Cho, J.-A. Seo, K. S. Yook and J. Y. Lee, *Chem. Mater.*, 2017, **29**, 1946; (d) Y. Liu, C. Li, Z. Ren, S. Yan and M. R. Bryce, *Nat. Rev. Mater.*, 2018, **3**, 18020.
- (a) Q. Zhang, B. Li, S. Huang, H. Nomura, H. Tanaka and C. Adachi, *Nat. Photonics*, 2014, **8**, 326; (b) M. Numata, T. Yasuda and C. Adachi, *Chem. Commun.*, 2015, **51**, 9443; (c) J. W. Sun, J. Y. Baek, K.-H. Kim, C.-K. Moon, J.-H. Lee, S.-K. Kwon, Y.-H. Kim and J.-J. Kim, *Chem. Mater.*, 2015, **27**, 6675; (d) I. S. Park, J. Lee and T. Yasuda, *J. Mater. Chem. C*, 2016, **4**, 7911; (e) T. Hatakeyama, K. Shiren, K. Nakajima, S. Nomura, S. Nakatsuka, K. Kinoshita, J. Ni, Y. Ono and T. Ikuta, *Adv. Mater.*, 2016, **28**, 2777; (f) L.-S. Cui, H. Nomura, Y. Geng, J. U. Kim, H. Nakanotani and C. Adachi, *Angew. Chem., Int. Ed.*, 2017, **56**, 1571; (g) P. Rajamalli, N. Senthilkumar, P.-Y. Huang, C.-C. Ren-Wu, H.-W. Lin and C.-H. Cheng, *J. Am. Chem. Soc.*, 2017, **139**, 10948; (h) Y. H. Lee, S. Park, J. Oh, J. W. Shin, J. Jung, S. Yoo and M. H. Lee, *ACS Appl. Mater. Interfaces*, 2017, **9**, 24035; (i) Y. H. Lee, S. Park, J. Oh, S.-J. Woo, A. Kumar, J.-J. Kim, J. Jung, S. Yoo and M. H. Lee, *Adv. Opt. Mater.*, 2018, **6**, 1800385; (j) Y. Wada, S. Kubo and H. Kaji, *Adv. Mater.*, 2018, **30**, 1705641; (k) X. Liang, Z.-P. Yan, H.-B. Han, Z.-G. Wu, Y.-X. Zheng, H. Meng, J.-L. Zuo and W. Huang, *Angew. Chem., Int. Ed.*, 2018, **57**, 11316; (l) D. H. Ahn, S. W. Kim, H. Lee, I. J. Ko, D. Karthik, J. Y. Lee and J. H. Kwon, *Nat. Photonics*, 2019, **13**, 540.
- (a) Y. Kitamoto, T. Namikawa, T. Suzuki, Y. Miyata, H. Kita, T. Sato and S. Oi, *Tetrahedron Lett.*, 2016, **57**, 4914; (b) J. W. Sun, J. Y. Baek, K.-H. Kim, J.-S. Huh, S.-K. Kwon,



- Y.-H. Kim and J.-J. Kim, *J. Mater. Chem. C*, 2017, **5**, 1027; (c) S.-J. Woo, Y. Kim, S.-K. Kwon, Y.-H. Kim and J.-J. Kim, *ACS Appl. Mater. Interfaces*, 2019, **11**, 7199; (d) S.-J. Woo, Y. Kim, Y.-H. Kim, S.-K. Kwon and J.-J. Kim, *J. Mater. Chem. C*, 2019, **7**, 4191.
- 9 (a) T. Nishimoto, T. Yasuda, S. Y. Lee, R. Kondo and C. Adachi, *Mater. Horiz.*, 2014, **1**, 264; (b) C. Fan, C. Duan, Y. Wei, D. Ding, H. Xu and W. Huang, *Chem. Mater.*, 2015, **27**, 5131; (c) J. Zhang, D. Ding, Y. Wei, F. Han, H. Xu and W. Huang, *Adv. Mater.*, 2016, **28**, 479; (d) J. Zhang, D. Ding, Y. Wei and H. Xu, *Chem. Sci.*, 2016, **7**, 2870; (e) D. Zhang, M. Cai, Z. Bin, Y. Zhang, D. Zhang and L. Duan, *Chem. Sci.*, 2016, **7**, 3355; (f) L.-S. Cui, J. U. Kim, H. Nomura, H. Nakanotani and C. Adachi, *Angew. Chem., Int. Ed.*, 2016, **55**, 6864; (g) I. S. Park, H. Seo, H. Tachibana, J. U. Kim, J. Zhang, S. M. Son and T. Yasuda, *ACS Appl. Mater. Interfaces*, 2017, **9**, 2693; (h) S. Y. Byeon, J. H. Kim and J. Y. Lee, *ACS Appl. Mater. Interfaces*, 2017, **9**, 13339; (i) S. Choi, M. Godumala, J. H. Lee, G. H. Kim, J. S. Moon, J. Y. Kim, D.-W. Yoon, J. H. Yang, J. Kim, M. J. Cho, J. H. Kwon and D. H. Choi, *J. Mater. Chem. C*, 2017, **5**, 6570; (j) M. Godumala, S. Choi, S. Y. Park, M. J. Cho, H. J. Kim, D. H. Ahn, J. S. Moon, J. H. Kwon and D. H. Choi, *Chem. Mater.*, 2018, **30**, 5005.
- 10 X.-L. Chen, J.-H. Jia, R. Yu, J.-Z. Liao, M.-X. Yang and C.-Z. Lu, *Angew. Chem., Int. Ed.*, 2017, **56**, 15006.
- 11 (a) J. Lee, N. Aizawa, M. Numata, C. Adachi and T. Yasuda, *Adv. Mater.*, 2017, **29**, 1604856; (b) J. Lee, N. Aizawa and T. Yasuda, *Chem. Mater.*, 2017, **29**, 8012; (c) Q. Zhang, D. Tsang, H. Kuwabara, Y. Hatae, B. Li, T. Takahashi, S. Y. Lee, T. Yasuda and C. Adachi, *Adv. Mater.*, 2015, **27**, 2096.
- 12 I. S. Park, K. Matsuo, N. Aizawa and T. Yasuda, *Adv. Funct. Mater.*, 2018, **28**, 1802031.
- 13 (a) W.-L. Tsai, M.-H. Huang, W.-K. Lee, Y.-J. Hsu, K.-C. Pan, Y.-H. Huang, H.-C. Ting, M. Sarma, Y.-Y. Ho, H.-C. Hu, C.-C. Chen, M.-T. Lee, K.-T. Wong and C.-C. Wu, *Chem. Commun.*, 2015, **51**, 13662; (b) T.-A. Lin, T. Chatterjee, W.-L. Tsai, W.-K. Lee, M.-J. Wu, M. Jiao, K.-C. Pan, C.-L. Yi, C.-L. Chung, K.-T. Wong and C.-C. Wu, *Adv. Mater.*, 2016, **28**, 6976; (c) K. Wang, C.-J. Zheng, W. Liu, K. Liang, Y.-Z. Shi, S.-L. Tao, C.-S. Lee, X.-M. Ou and X.-H. Zhang, *Adv. Mater.*, 2017, **29**, 1701476.
- 14 (a) R. Furue, T. Nishimoto, I. S. Park, J. Lee and T. Yasuda, *Angew. Chem., Int. Ed.*, 2016, **55**, 7171; (b) N. Aizawa, C.-J. Tsou, I. S. Park and T. Yasuda, *Polym. J.*, 2017, **49**, 197; (c) J. Huang, H. Nie, J. Zeng, Z. Zhuang, S. Gan, Y. Cai, J. Guo, S.-J. Su, Z. Zhao and B. Z. Tang, *Angew. Chem., Int. Ed.*, 2017, **56**, 12971; (d) H. Liu, J. Zeng, J. Guo, H. Nie, Z. Zhao and B. Z. Tang, *Angew. Chem., Int. Ed.*, 2018, **57**, 9290; (e) J. Guo, Z. Zhao and B. Z. Tang, *Adv. Opt. Mater.*, 2018, **6**, 1800264.
- 15 A few TADF molecules containing acridan-based donors were recently reported to show both QE and QA conformations: (a) W. Li, X. Cai, B. Li, L. Gan, Y. He, K. Liu, D. Chen, Y.-C. Wu and S.-J. Su, *Angew. Chem., Int. Ed.*, 2019, **58**, 582; (b) K. Wang, C.-J. Zheng, W. Liu, K. Liang, Y.-Z. Shi, S.-L. Tao, C.-S. Lee, X.-M. Ou and X.-H. Zhang, *Adv. Mater.*, 2017, **29**, 1701476; (c) N. A. Kukhta, A. S. Batsanov, M. R. Bryce and A. P. Monkman, *J. Phys. Chem. C*, 2018, **122**, 28564.
- 16 (a) H. Tanaka, K. Shizu, H. Nakanotani and C. Adachi, *J. Phys. Chem. C*, 2014, **118**, 15985; (b) S. Xu, T. Liu, Y. Mu, Y.-F. Wang, Z. Chi, C.-C. Lo, S. Liu, Y. Zhang, A. Lien and J. Xu, *Angew. Chem., Int. Ed.*, 2015, **54**, 874; (c) Z. Xie, C. Chen, S. Xu, J. Li, Y. Zhang, S. Liu, J. Xu and Z. Chi, *Angew. Chem., Int. Ed.*, 2015, **54**, 7181; (d) B. Xu, Y. Mu, Z. Mao, Z. Xie, H. Wu, Y. Zhang, C. Jin, Z. Chi, S. Liu, J. Xu, Y.-C. Wu, P.-Y. Lu, A. Lien and M. R. Bryce, *Chem. Sci.*, 2016, **7**, 2201; (e) M. Okazaki, Y. Takeda, P. Data, P. Pander, H. Higginbotham, A. P. Monkman and S. Minakata, *Chem. Sci.*, 2017, **8**, 2677; (f) M. K. Etherington, F. Franchello, J. Gibson, T. Northey, J. Santos, J. S. Ward, H. F. Higginbotham, P. Data, A. Kurowska, P. L. Dos Santos, D. R. Graves, A. S. Batsanov, F. B. Dias, M. R. Bryce, T. J. Penfold and A. P. Monkman, *Nat. Commun.*, 2017, **8**, 14987; (g) D.-G. Chen, T.-C. Lin, Y.-A. Chen, Y.-H. Chen, T.-C. Lin, Y.-T. Chen and P.-T. Chou, *J. Phys. Chem. C*, 2018, **122**, 12215; (h) C. Chen, R. Huang, A. S. Batsanov, P. Pander, Y.-T. Hsu, Z. Chi, F. B. Dias and M. R. Bryce, *Angew. Chem., Int. Ed.*, 2018, **57**, 16407; (i) Y. Takeda, T. Kaihara, M. Okazaki, H. Higginbotham, P. Data, N. Tohnai and S. Minakata, *Chem. Commun.*, 2018, **54**, 6847.
- 17 (a) H. Sun, C. Zhong and J.-L. Brédas, *J. Chem. Theory Comput.*, 2015, **11**, 3851; (b) T. Penfold, *J. Phys. Chem. C*, 2015, **119**, 13535.
- 18 (a) C. Reichardt, *Chem. Rev.*, 1994, **94**, 2319; (b) J. P. Cerón-Carrasco, D. Jacquemin, C. Laurence, A. Planchat, C. Reichardt and K. Sraïdi, *J. Phys. Org. Chem.*, 2014, **27**, 512.
- 19 (a) T. Förster, *Z. Elektrochem.*, 1950, **54**, 531; (b) A. Weller, *Z. Elektrochem.*, 1952, **56**, 662.
- 20 S. Y. Lee, C. Adachi and T. Yasuda, *Adv. Mater.*, 2016, **28**, 4626.
- 21 (a) M. K. Etherington, J. Gibson, H. F. Higginbotham, T. J. Penfold and A. P. Monkman, *Nat. Commun.*, 2016, **7**, 13680; (b) F. B. Dias, J. Santos, D. R. Graves, P. Data, R. S. Nobuyasu, M. A. Fox, A. S. Batsanov, T. Palmeira, M. N. Berberan-Santos, M. R. Bryce and A. P. Monkman, *Adv. Sci.*, 2016, **3**, 1600080; (c) J. Gibson, A. P. Monkman and T. J. Penfold, *ChemPhysChem*, 2016, **17**, 2956.
- 22 N. Aizawa, S. Shikita and T. Yasuda, *Chem. Mater.*, 2017, **29**, 7014.

